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Bib Data Sheet

CONFIRMATION NO. 1294

SERIAL NUMBER 09/945,247	FILING DATE 08/31/2001 RULE	CLASS 257	GROUP ART UNIT 2811	ATTORNEY DOCKET NO. 9319T-000281
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## APPLICANTS

Seiichiro Higashi, Chino-city, JAPAN;  
 Daisuke Abe, Suwa-city, JAPAN;

## \*\* CONTINUING DATA

*None in S*

## \*\* FOREIGN APPLICATIONS

JAPAN 2000-267286 09/04/2000  
 JAPAN 2001-263559 08/31/2001

*Yes in S*

## IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 10/04/2001

Foreign Priority claimed	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no		
35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance		
Verified and Acknowledged	<i>Att. Examiner in S</i> Examiner's Signature Initials		
STATE OR COUNTRY	SHEETS DRAWING	TOTAL CLAIMS	INDEPENDENT CLAIMS
JAPAN	7	16	4

## ADDRESS

27572

## TITLE

Method for fabrication of field-effect transistor *to Reduce Defects At MOS Interfaces formed*

FILING FEE RECEIVED 954	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
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